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Experimental and Theoretical Investigations of Low-Dimensional BiFeO$_3$ System for Photocatalytic Applications

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Abstract: We report on the fabrication of sub-20 nm BiFeO$_3$ (BFO) nanoparticles using a solid-state approach and preferential leaching process. The nanoparticles were subsequently used to deposit, through spray pyrolysis, BFO thin films in a rhombohedral (R3c) crystallographic structure. Then, systematic investigations of the optical and the photocatalytic properties were conducted to determine the effects of the particles size, the microstructure and the increased surface area on their catalytic performances. Especially, improved optical properties were observed, with an optical bandgap energy of 2.20 eV compared to reported 2.7 eV for the bulk system. In addition, high optical absorption was obtained in the UV–visible light region reaching up to 90% at 400 nm. The photoelectrochemical measurements revealed a high photocurrent density under visible light irradiation. Besides, density functional theory calculations were performed on both bulk and thin film BFO structures, revealing an interesting comparison of the electronic, magnetic, ferroelectric and optical properties for bulk and thin film BFO systems. Both theoretical and experimental findings show that the alignment of the band edges of BFO thin film is coherent with good photocatalytic water splitting potential, making them desirable photoanode materials.

Keywords: photocatalysis; BiFeO$_3$ nanoparticles; high energy ball milling; spray pyrolysis; photoelectrochemical measurements; density functional theory

1. Introduction

Energy demand in recent years has shown significant growth owing to the world’s growing population and constant development of technology-based industries. Currently, fossil fuels constitute the most dominant energy consumption. Nevertheless, their carbon footprint and harmful gas emissions are at the forefront of environmentally impactful dangers both on peoples’ and the globe’s health [1,2]. To meet the world’s energy needs and support the energy transition to clean and sustainable energy consumption, it is necessary to focus on the development of alternative clean energy resources. Harnessing sunlight energy is perhaps one of the most straightforward and continuously available routes to produce energy on demand clean, sustainable and renewable. Among an important diversity of methods to exploit the solar energy, producing hydrogen through the splitting of water molecules into its constituent elements has recently attracted a lot of interest [3,4]. Nonetheless, a few essential conditions have to be fulfilled in order to produce an efficient Water Splitting (WS) device. The nature of the photocatalyst material is the first and
main component to consider. In this context, several materials have been studied for their photocatalytic activity in the race for the optimal photocatalyst capable of generating a large quantity of hydrogen. Metal oxides were largely investigated as photocatalysts (ex: TiO$_2$, SnO$_2$, Fe$_2$O$_3$, ZnO) owing to their high stability, efficiency, and especially their low cost [5–8]. Since Fujishima and Honda (1972) brought to light the benefit of TiO$_2$ single crystal for solar water splitting, many interesting findings were proposed by various researcher groups all over the world [9]. Despite their high potential, the light absorption of metal oxides is limited within the ultra-violet region, which reduces significantly their solar-to-hydrogen (STH) conversion efficiency. Nevertheless, surface modification using plasmonic materials has been reported to significantly enhance the visible light absorption of the photocatalyst [10–14] as well as improving the efficiency of the charge separation and amplification of the electron-hole (e–h) pairs. However, oxidation of the material with the aqueous solution remains a challenging drawback in this case [15].

Recently, perovskite materials (PMs) have emerged as potentially interesting photocatalysts owing to their high electrochemical and photophysical properties [16,17]. The exceptional structural flexibility of PMs allows the design of WS devices with high STH efficiency, thanks to the precise control of the composition, the electronic structure, and the morphology of this class of materials. Particularly, the ferroelectric properties present in PMs were found to promote the photocatalytic activities [18,19]. For instance, the PbTiO$_3$ compound was reported to have an effective charge separation and good photocatalytic performance which were attributed to its ferroelectric properties [20]. Therefore, owing to their high photocatalytic potential, good stability, structural flexibility, ease of synthesis, and ferroelectric properties, PMs show a high potential for the development of more efficient future water splitting devices. Furthermore, the BFO photocatalyst has already been demonstrated for the degradation of organic compounds such as dyes [21–23], antibiotics [24], and antibacterials [25], as well as a photoanode for hydrogen production [26]. The BFO photocatalytic activity (band gap engineering and restriction of the recombination rate) was also found to be improved by the incorporation of doping agents such as La [27–29], Sm [30], co-catalyst [31], metallic nanoparticles such as gold [32] or silver [33] or by the production of n/p heterojunction [34–36].

This work is focused on the elaboration, characterization and the photocatalytic performances of low-dimensional BFO films deposited by means of spray pyrolysis. Besides, density functional theory is used to investigate the effect of the dimensionality on the optical and photocatalytic properties of the BFO system.

2. Results and Discussion
2.1. Thermal Analysis

Figure 1 presents the thermogravimetric (TGA) and differential scanning calorimetry (DSC) curves of as-milled Bi$_2$O$_3$ and Fe$_2$O$_3$ mixture in the range of 40 °C to 1100 °C.

As can be seen, the formation of the BFO compound is a complex multi-step reaction process. It is worth noting that the bismuth oxide and the iron oxide are highly hygroscopic oxides prone the moisture uptake in the humid environment. Hence, the first step (40–200 °C) of the weight loss (~1%) could be attributed to the water evaporation along with ethanol solvent used to prepare the BFO powder by the high energy ball milling. At intermediate temperatures, the weight shows abrupt losses about ~2.7% and ~1.5% in the range 200–350 °C, and 350–460 °C, respectively. The first weight loss was reported by Maurya et al. [37] to be induced by the volatilization of bismuth, while the second weight loss is ascribed to the formation of intermediate compounds as reported earlier by Valant et al. [38]. These authors suggested that metallic bismuth compounds could be released, considering the melting point of bismuth oxide is 825 °C. Similar results were reported by Sharma et al. [39] who extensively investigated the formation of bismuth ferrite using a solid-state reaction by TGA/DSC technique. These authors reported that during the synthesis of the BFO compound, the formation of secondary phases, such as Bi$_2$Fe$_4$O$_9$ and/or Bi$_{25}$FeO$_{40}$, might occur. Regarding the temperature region from 460 °C to 900 °C, no mass change was noticed, however, the
DSC curve exhibits a large corresponding exothermic peak. This last response is a signature of the temperature of crystallization of the BFO system. Based on the TGA/DSC experiments, a temperature of 700 °C was selected for further BFO powder heat treatment. Furthermore, a strong endothermic peak is observed at 936 °C which could be attributed to the melting point of the BFO compound. The high mass loss observed above 1000 °C is most probably related to Bi$_2$O$_3$ evaporation, as previously reported by Palai et al. [40].

![Combined thermogravimetric (TGA) and differential scanning calorimetry (DSC) results](image)

**Figure 1.** Combined thermogravimetric (TGA) and differential scanning calorimetry (DSC) results obtained on as-milled Bi$_2$O$_3$ and Fe$_2$O$_3$ mixture.

### 2.2. X-ray Diffraction

Figure 2 depicts the room temperature X-ray diffractogram of the BFO sample, as fabricated and leached ones at the most relevant diffracting windows for BFO (20° to 60°).

![X-ray diffraction patterns](image)

**Figure 2.** X-ray diffraction patterns of BiFeO$_3$ compound for (red) as received sample, (black) after the first and (blue) second leaching with acetic acid. (*) indicates Bi$_{25}$FeO$_{40}$ picks positions.

The red plot presents the calcined sample at 700 °C for 1 h. A typical rhombohedral structure is obtained along with a non-negligible secondary phase assigned to the Bi$_{25}$FeO$_{40}$ phase. To remove these impurities, two leaching steps were carried out using glacial acetic acid [41,42]. The second black curve shows the obtained BFO XRD spectra after the first leaching (24 h) which seems to drastically decrease the quantity of undesired phases. To achieve a complete removal of the Bi$_{25}$FeO$_{40}$ secondary phase, a second leaching (48 h)
was done (blue curve), after which no impurity could be detected with a final pure R3c BFO structure. From the XRD pattern of the pure BFO system, we could extract the lattice parameters in the rhombohedral structure with $a = 5.635 \text{ Å}$, and $\alpha = 59.3918^\circ$.

2.3. Raman Spectroscopy

To further confirm the phase purity of the prepared sample, a micro-Raman (Renishaw) spectrometer was used to examine the vibrational behavior of the obtained BFO structure. The energy excitation used for the analysis is a green laser (532 nm). Figure 3a presents the Raman spectrum of the leached BiFeO$_3$ sample collected at room temperature from 50 to 550 cm$^{-1}$.

The deconvoluted BFO Raman spectrum (Figure 3b) evidences well the presence of the 13 Raman modes, i.e., nine $E$ modes, and four $A_1$ modes, with the irreducible representation: $\Gamma = 4A_1 + 9E$, of the rhombohedral (R3c) structure of pure BFO system [43–45]. Note that the low-frequency Raman modes, $E(1) \sim 75$ cm$^{-1}$, $E(2) \sim 110$ cm$^{-1}$, $A_1(1) \sim 138$ cm$^{-1}$, $A_1(2) \sim 171$ cm$^{-1}$ are assigned to bismuth vibrations and oxygen octahedral tilt in the R3c structure. On the other hand, the middle-frequency Raman modes, $A_1(3)$, $E(3)$, and $E(4)$ correspond to the vibrations associated to iron atoms [46]. Regarding the high-frequency Raman modes, they are mainly correlated to the motion of oxygen atoms [47–49].

2.4. Microstructure Analysis

After obtaining high purity BFO powders, we investigated the effect of a second stage of a high energy ball milling step of the initial powder. Figure 4 shows the scanning electron microscopy (SEM) images collected of the sprayed BiFeO$_3$ films with different initially milled powders.

Figure 4a,b presents the BFO sample with no second milling at different magnifications. It can be observed that the surface is not homogenous with regions where grains are aggregated. From Figure 4b, the grain size was observed to vary from 200 to 400 nm. Figure 4c,d presents the sprayed BFO sample from an initial powder with a second 8 h high energy ball milling step. It can be observed that in this case grain size lower than 100 nm was achieved. The obtained results are beneficial to photocatalytic applications owing to the high surface area, high crystallinity confirmed by Raman spectroscopy and free of defects (dislocations), as shown in transmission electron microscopy (TEM) investigations given below. This allows low e-h recombination leading to higher water splitting activity.

TEM investigations were carried out on the BFO nanoparticles obtained after 8 h ball milling and a bright field low magnification micrograph is depicted in the Figure 5a. At this magnification, the particles appear as an aggregate set, while the high-resolution micrographs depicted in Figure 5b,c demonstrate the nanometric scale of the milled particles. The nanoparticle size distribution is extracted and provided in Figure 5d. The crystal size varies from few nm to few tens of nm, with an average size in the range of 5–10 nm.
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Figure 5. TEM images of the BFO nanoparticles. (a) A bright field TEM image of a set of particles. (b,c) HRTEM images of nanoparticles with different shapes and sizes. (d) The size distribution of the BFO nanoparticles implying the dominant size in the range of 5-10 nm.

2.5. Optical Properties

It should be noted that the absorption in the visible light region of materials is an important parameter to consider for water splitting applications where solar light needs to be mostly absorbed to improve the water splitting efficiency.
Figure 6a presents the absorption, transmittance, and reflectance response of BFO film with no second milling step, where the response of the glass substrate was subtracted.

![Graphs showing absorption, transmittance, and reflectance](image)

**Figure 6.** Absorption, transmittance, and reflectance of BiFeO$_3$ deposited on a glass substrate with (a) no second milling, (c) with 8 h of second milling of the initial powder. Their respective Tauc plots are illustrated in (b,d).

The absorption curve of BFO shows two main peaks, a first dominant response (~75%) in the UV range, and a second one in the visible light region (~40%). The obtained response is very interesting and proves the potential of our prepared films to be good photocatalysts. We also investigated the optical band gap of the sample (shown in Figure 6b) using the Tauc relation: $(\alpha h\nu)^n \propto (h\nu-E_g)$ where $n = 2$ stand for a direct bandgap. Therefore, from the intersection of the extrapolated linear part of $(\alpha h\nu)^2$ versus energy with the energy axis, we could extract the bandgap energy of our sample. A direct band gap energy of 2.20 eV was found for the BFO sample. It is worth mentioning that the usually reported band gap value of the bulk BFO compound is ranging from 2.5 to 2.8 eV [50,51]. Note that Mocherla et al. [52] demonstrated that the bandgap energy value of the BFO system is directly related to the grain size, such that a lower band gap energy can be obtained for samples presenting smaller grain sizes.

Figure 6c presents the absorption, transmittance, and reflectance response of BFO film with a second milling of 8 h. An important increase in the absorption is noticed for wavelengths from 200 to 500 nm, achieving a maximum absorption of ~90% (400 nm). Especially, we can observe an increase in the absorption for wavelengths superior to 600 nm, reaching 15% of absorption at 600 nm instead of 4% for the sample with no second ball milling. The energy band gap of this sample (Figure 6d) was also found to be 2.20 eV.

Therefore, one can say that our original methodology permitted us to achieve high absorption in the UV and visible light region, with a corresponding band gap value of ~2.20 eV, making it an interesting candidate for photocatalysis.

2.6. Photoelectrochemical Measurements

In this section, the potential of the BFO sample for photocurrent generation is examined. Figure 7a present the Mott–Schottky plot $1/C^2(E)$ of BFO film deposited on a Pt/Si...
substrate. From the resulting positive slope, we can conclude about an n-type semiconductor type with a flat band potential $E_{fb} = -0.38$ V vs. Ag/AgCl or 0.231 V vs. RHE (at pH = 7). Potentials vs. Ag/AgCl were converted to potentials vs. RHE with following equation [53]:

$$E_{(RHE)} = E_{(Ag/AgCl)} + E^0_{(Ag/AgCl)} + 0.0591 pH$$  \hspace{1cm} (1)

where $E^0_{(Ag/AgCl)}$ (reference electrode, saturated KCl) = 0.197 V vs. NHE at 25 °C.

In the depletion zone, a plateau is observed, slightly shifting the flat band potential. This offset may be due to the presence of electrically active defects in the surface (surface states) inducing a Helmholtz layer capacitance as reported [54]. The flat band potential reflects the position of the Fermi level as described [55]. For the n-type semi-conductor, the conduction band (CB) edge is expected to be located very close to 0.1 V of its flat band potential [56]. Therefore, knowing the band gap value, we could locate, respectively,

**Figure 7.** (a) Mott–Schottky plot. (b) Transient photocurrent response under illumination and dark conditions of BFO thin film for various wavelengths ranging from 450 to 627 nm ($\phi = 62$ mW/cm$^2$). (c) Transient photocurrent response (On–Off cycles every 20 s) as a function of the incident light intensity ($\lambda = 450$ nm, and $V = 0.6$ V vs. Ag/AgCl). (d) The evolution of $\Delta j$ ($\phi$) for $\lambda = 450$ and 627 nm and the fit in dashed lines. (e) Transient photocurrent response registered for six cycles ON/OFF (every 20 s) and under constant solar simulator of 100 mW/cm$^2$. (f) Photosensitivity of BFO thin film sample as a function of wavelength.
conduction and valence band edges of processed BFO film at neutral pH at $E_{CB} \approx 0.131$ V vs. NHE, and at $E_{VB} \approx 2.331$ V vs. NHE.

To determine the transient photocurrent, a three-electrode cell, consisting of Ag/AgCl reference electrode, Pt wire as counter electrode, and the working electrode made of BFO film grown on Pt/Si substrate, is used and a solution 0.1 M of $\text{Na}_2\text{SO}_4$ is employed as an electrolyte. Figure 7b presents the transient photocurrent response of BFO film under different excitation wavelengths. One can observe the presence of a non-negligible photocurrent for low wavelengths of $\sim 10 \mu$A/cm$^2$ (450 nm) under a light intensity of $\phi = 62$ mW/cm$^2$ using a bias potential of 0.6 V vs. Ag/AgCl. For the higher excitation wavelengths, the maximum photocurrent decreases but remains significant. For further investigations, in Figure 7c, the photocurrent response ($\Delta j$) is measured as a function of the light intensity ($\phi_0$ in mW·cm$^{-2}$) for constant $\lambda = 450$ nm and $V_{bias} = 0.6$ V vs. Ag/AgCl.

The dependence of the photocurrent on the incident light intensity (Figure 7c) highlights a linear evolution for BFO films ($\Delta j = A\phi_0$ where $A$ is a wavelength-dependent constant). Indeed, this linear behavior is also observed for other wavelengths (e.g., $\lambda = 627$ nm in Figure 7d). Theoretically, the evolution of the photocurrent as a function of the incident light intensity follows a power law of type $\Delta j = A\phi_0^n$ where $A$ is a wavelength-dependent constant and $n$ a constant (that determines the photosensitivity of the oxide and whose value is less or equal to 1 [57]). In our case, the exponent is equal to 1, which indicates that the process of generating e-h pairs takes place without the influence of trapping phenomena or recombination in unlit areas at this applied bias voltage [58,59]. This result is not surprising because in thin films, thus for small values of the thickness, the illumination is appreciably uniform and $\Delta j$ varies linearly with $\phi_0$. When thickness increase, the absorption becomes non-uniform in thickness, hence the recombination in the unlit domain increases and the $n$ exponent decreases, its value limit must be 0.5 for very large thicknesses [59].

Figure 7e presents a transient photocurrent response obtained under a solar simulator equivalent to 1 sun (100 mW/cm$^2$, AM 1.5G) and for applied bias voltage of 0.6 V. It is observed the achievement of an important photocurrent density of 40 $\mu$A/cm$^2$ within the BFO sample. It is worth noting that the notable photocurrent is generated from as low as an applied voltage of 0.1 V. Besides, a slight decrease of the photocurrent response (see arrow in Figure 7e) is observed, which could be attributed to the degradation of BFO due to the electrolyte. Indeed, BFO contains iron, which is a corrosive material in contact with Na$_2$SO$_4$ solution. The obtained photosensitivity ($\mu$A/W) of the BFO sample as a function of wavelength (Figure 7f) is in good accordance with the optical measurements presented above. The best efficiency is obtained for low wavelengths, but a photocurrent is produced over the entire visible spectral range. Finally, the position of the valence and conduction bands determined experimentally and the high photocurrent generated in the visible range suggest that the BFO thin film exhibits a great potential to be used as photoanodes within water-splitting photoelectrochemical systems.

2.7. Theoretical Calculations
2.7.1. Electronic Properties

Note that the magnetic properties of the BFO system were considered in our calculations, and both ferromagnetic (FM) and antiferromagnetic (AFM) configurations were studied. It was found that the lowest energy was obtained for the AFM configuration of the BFO system, which agrees well with the literature review [60,61]. In addition, we used two different approximations to ensure the accurate description of the electronic properties of the studied AFM bulk BFO system (Figure 8). We first considered the generalized gradient approximation (GGA) to consider the effect of gradients into the charge density, which is known to improve the calculation of the cohesive energy. From Figure 8, we can observe an extremely low band gap energy of 0.5 eV using the GGA approximation which is still far from the well-known band gap of BFO system (i.e., $\sim 2.7$ eV) [50,51].
In a view to correct the description of the electronic properties, we implemented our calculations with the Tran and Blaha modified Becke–Johnson (TB-mBJ) exchange potential. The TB-mBJ approximation yields particularly good electronic properties [62], with the achievement of an energy band gap of 2.5 eV, in good accordance with a literature review [63,64].

Figure 9 presents the band structure obtained using the different approximations. Interestingly, it can be seen from the figure that both the nature and the energy of the band gap are different depending on the used approximation. An indirect band gap is observed for the GGA approximation. However, a direct band gap of 2.5 eV can be observed for the GGA + TB-mBJ approximation. Note that several experimental articles reported a direct band gap for BiFeO$_3$ system [65–67]. Therefore, our calculations permitted us to achieve $E_g$ values closer to the experiment.

Figure 10a presents the total and partial density of electronic states of the BiFeO$_3$ system calculated using the GGA + TB-mBJ approximation. It can be observed from the figure, that owing to the antiferromagnetic ordering considered in our calculations, the spin up and spin down channels are equal with a zero-net total magnetization. Note that both the valence band and the conduction band are constituted of oxygen 2p orbitals, iron 3d, and bismuth 6p orbitals, which reveal the strong Bi-O and Fe-O hybridization. In addition, we can conclude about a strong interaction between bismuth, iron and oxygen atoms, which is confirmed from the electronic density plot presented in Figure 10b. Indeed, Bi and Fe ions are observed to share covalent bonding with oxygen atoms.
Since the BFO system, in its rhombohedral structure, is known to present ferroelectric properties, we were also interested in the calculation of the polarization value using the BerryPI approach [68]. Our calculations showed a high polarization value of 83 µC/cm² in the [111] direction for the bulk AFM BFO system. Note that the high polarization value observed in BFO is in part related to the lone pair effect (6s²) of bismuth atoms [69].

In a view to investigate the effect of dimensionality on BFO system, we also investigated the electronic properties of BiFeO₃ in the thin film form. Figure 11a presents the total and partial density of electronic states of BFO thin film. On the contrary to the bulk system, we can note here that the spin up and spin down channels are not equal even though antiferromagnetic ordering was considered. Fact that resulted in a net non-zero magnetization of \( M = 2 \mu_B \) in the BFO thin film. Remind that to simulate thin films we used a 10 Å vacuum in the z-direction. The induced degree of freedom in the z-direction may have resulted in canted/non-collinear arrangement of spins in the surface. Therefore, the enhanced magnetization in the BFO thin film can be attributed to the canting effect in the surface owing to the uncompensated magnetic moments of iron ions.

Indeed, several works reported on the influence of the magnetic field on hydrogen production via water splitting. For instance, Karatza et al. reported a non-negligible hydrogen generation of 0.229 mg from water through a magnetic pre-poling (\( M = 48.3 \) mT) of the \( \text{Fe}_3\text{O}_4 \) system [70]. The magnetic pre-poling was demonstrated to induce re-orientations of
the magnetic poles of each grain making them behave like small magnets and results in the stabilization of the borders between grains [71]. Besides, the presence of both electric and magnetic properties in multiferroic materials permits the manipulation of the magnetism via electric fields and electricity via magnetic fields thanks to the magnetoelectric coupling [72].

Interestingly, the polarization was observed to increase to 93 µC/cm² for BFO thin films in the [111] direction. The obtained polarization value matches well with reported experimental studies on BFO thin films [73,74]. We plotted in Figure 11b the charge density distribution of BFO thin film, in a view to investigate the origin of the increased ferroelectricity in the system.

Interestingly, a stronger Bi-O and Fe-O bonding (smaller bond length) can be observed in the BFO thin film compared to the bulk one, which can explain the enhanced polarization value obtained in the thin film. Figure 12a,b presents the spin up and spin down parts of the band structure of BiFeO₃ thin film. Note that a direct band gap is observed in both figures with band gap values of 1.6 eV (up) and 2 eV (down). This feature is very interesting and implies that in such system a desired band gap can be promoted using appropriate excitation. In the view to investigate the absorption of the spin up and spin down of BFO system, we plotted in Figure 13a,b the Fe 2p X-ray absorption spectra (XAS), and X-ray magnetic circular dichroism (XMCD) of BiFeO₃ system in both bulk and thin film form.

Regarding the XAS curves, we can observe from the figures two peak responses related to L₃(2p₃/2) and L₂(2p₁/2) states. The intensity ratio (I(L₂)/I(L₃)) of L₂ and L₃ is found to be ~0.73 for the bulk and ~0.67 for thin film BFO. The decreased intensity ratio indicates an enhanced effect of surface state for the thin film BFO system, as has been reported previously [75,76].
Besides, owing to the octahedral ligand field, the L₂ and L₃ peaks further split to t₂g and e₅ states. Hence, through the deconvolution of the XAS curves we could extract the crystal-field splitting of the BFO system (i.e., energy difference between t₂g and e₅ states). A crystal-field value of 1.24 and 1.02 eV was found for BFO thin film, and bulk, respectively, which indicates the presence of a different titanium octahedral environment. In addition, the use of circular polarized light in the X-ray magnetic circular dichroism study makes the absorption signal of the studied element (i.e., iron) sensitive to the magnetic moment. The blue line in Figure 13 illustrates the XMCD signal of Fe L₂,3 edge which represents the difference value between the left and right circular polarized XAS spectra.

2.7.2. Optical Properties

In this part, we investigated the optical properties of BFO system in its bulk and thin film form using the mBJ approximation. Note that the absorption coefficient, \( \alpha(\omega) \), was calculated using the following equation:

\[
\alpha(\omega) = \sqrt{2\omega} \sqrt{\epsilon_1(\omega) + \epsilon_2(\omega)} - \epsilon_1(\omega)
\]

where \( \epsilon_1(\omega) \) and \( \epsilon_2(\omega) \) stand for the real and imaginary parts of the dielectric permittivity, respectively. Figure 14 illustrates the Tauc plots of the BFO system in its bulk and film form, extracted from DFT calculations. It is worth mentioning that in the last years there has been a great number of theoretical investigations reporting on the optical properties of bulk BFO system [77–80]. However, the reported band gap values, as recently demonstrated, are usually misestimated due to the used approximations (e.g., local density and generalized gradient approximations), leading to a truncated description of the strong Coulomb and exchange interactions in transition metal oxides [81]. For instance, using the local spin density approximation (LSDA), Neaton et al. [80] reported an underestimated band gap of 1.9 eV, whereas using the Heyd–Scuseria–Ernzerhof (HSE) screened hybrid functional, Stroppa et al. overestimated the band gap of BFO system to 3.4 eV [79]. In this work, the use of the GGA + TB-mBJ approximation led us to approach quite well the experimental value [50,51], since we have found a direct optical band gap of 2.7 eV for the bulk BFO system (Figure 14a). Indeed, such approximation was previously demonstrated to reproduce rigorously the shape of the exact exchange potential for atoms [82]. In its thin film form, the band gap value of the BFO system was observed to decrease to 2.22 eV (Figure 14b), while keeping the direct band gap nature. Note that it is usually rather difficult to compare the theoretical results (e.g., band gap) of thin films to the experimental ones, since the properties are mainly dependent on various other parameters such as the particle size, morphology, and film thickness [81]. However, in our work the computed band gap value of BFO film appears to be in accordance with the experimental one. The decrease of the band gap in the film form is very interesting for photocatalytic applications, since it presents improved absorption in the visible light region.

![Figure 14. Tauc plot (n = 2, direct band gap) of (a) bulk BFO, (b) BFO thin film extracted from DFT.](image-url)
2.7.3. Photocatalytic Properties

Remember that when a photocatalyst material is irradiated by an energy of incident light higher than its band gap, a charge separation occurs with an electron-hole pair separation causing H$_2$ and O$_2$ generation. Hence, the photoexcited electrons in the conduction band (CB) take part in the reduction of water molecules to form H$_2$ gas (2H$^+$ + 2e$^-$ → H$_2$), whereas the holes in the valence band (VB) are responsible for water oxidation and produce O$_2$ gas (H$_2$O + 2h$^+$ → 2H$^+$ + 1/2 O$_2$). To efficiently split water molecules, the photocatalyst material should satisfy some basic criteria. First, the material must have a minimum band gap of 1.23 eV ($\lambda = 1000$ nm) to satisfy the redox potential of water. In addition to that, the potential of the top of the valence band (VB) should be higher than the redox potential O$_2$/H$_2$O (+1.23 V vs. NHE), and the bottom of the CB should be lower than the redox potential of H$^+$/H$_2$ (0 V vs. NHE) [83]. It has been largely reported that the adequate band gap value of the photocatalyst material should be in the range of 1.6–2.4 eV to efficiently satisfy the activation barrier of the multi-step water splitting reactions [83–85]. The conduction band minima, and valence band maxima of our systems (at pH = 0), were computed using Equations (3) and (4), and at specific pH using Equation (5) [86,87]:

\[ E_{CB}^{pH=0} = \frac{1}{2} E_g + \chi_{BFO} + E_0 \]  
\[ E_{VB}^{pH=0} = \frac{1}{2} E_g + \chi_{BFO} + E_0 \]  
\[ E_{(CB,VB)}^{pH} = E_{(CB,VB)}^{pH=0} - 0.05911 \times \text{pH} \]

where $E_0$ represents the scale factor used to link the absolute vacuum scale to the reference redox level ($E_0 = -4.5$ eV) [86], $E_g$ stands for the band gap energy, and $\chi_{BFO}$ is the absolute electronegativity of BiFeO$_3$ system. Note that the absolute electronegativity of BFO is given by: $\chi_{BFO} = (\chi_{Bi} \chi_{Fe} \chi_{O})^{1/3}$, where $\chi_{Bi} = 4.69$, $\chi_{Fe} = 4.06$, and $\chi_{O} = 7.54$ are the absolute electronegativities of Bi, Fe, and O elements [88].

Figure 15 presents a comparison of the band alignment of BFO thin film computed using Equation (5) and the experimental one extracted from the Mott–Schottky plot at pH = 7. As shown in the figure, both valence and conduction band edges extracted theoretically and experimentally are observed to concord, where $E_{VB}$ is observed to be more positive than the reduction potential of water which allows the occurrence of the oxygen evolution reaction. Our results reveal the potential of reducing dimensionality in the BFO system and should motivate the development of low-dimensional BFO-based films as potential photocatalyst materials and photoanode for water splitting reaction.

![Figure 15. Band alignment of BiFeO$_3$ thin film extracted experimentally and computed theoretically.](image)
3. Materials and Methods

As a first stage, a special focus was given to the elaboration of nanostructured transition metal oxide perovskite BiFeO$_3$ with controlled grain size through a solid-state synthesis approach by means of the high energy ball milling system. The elaborated BFO powder was used to prepare a solution to be subsequently deposited on glass substrate by means of spray pyrolysis to obtain a neat BFO film. Details of the experimental setup are given in the following paragraph.

First, stoichiometric amounts of bismuth oxide (Bi$_2$O$_3$, 99.99%), and iron oxide (Fe$_2$O$_3$, 99.99%) were weighed and mixed in an ethanol media to be processed by high energy ball milling operating at 1000 rpm for 2 h (Retsch GmbH, Haan, Germany). The high applied rotation speed is expected to achieve BFO powders with small grain size, which would significantly affect the resulting physical properties in comparison with the bulk BFO system. Thereafter, the resulting dried powder was uniaxially pressed into pellets, and placed into a muffle furnace at 700 °C for 1 h at a corresponding cooling/heating rate of 5 °C/min. The resulting pellet was then crushed and pressed in an agate mortar.

The leaching of the powder was performed using glacial acetic acid (99%) to remove the secondary phases. The leached residue was therefore washed with a large volume of distilled water to neutralize the acidity. Both TGA and DSC experiments were performed on the prepared BFO powder using a heating rate of 5 °C/min, in an Argon atmosphere (Netzsch GmbH, Selb, Germany). The phase purity of the resulting powder was investigated using a Brucker X-ray diffractometer (XRD) (CuK$_\alpha$ = 1.5406 Å).

A second high energy ball milling step of 8 h at 1000 rpm was added to the pure powder to investigate the effect of grain size decrease on the physical properties of BFO system. Thence, spray pyrolysis technique was used to subsequently deposit BFO on a desired substrate. A glass substrate was used to characterize the optical properties, whereas a silicon substrate with a sputtered Pt coating was used to investigate the photoelectrochemical properties of BiFeO$_3$ compound. Before deposition, we first prepared the precursor solution using a molar concentration of 0.1 M in ethanol. Therefore, the solution was stirred in an ultrasonic bath for 1 h until complete dilution. During the deposition process, the prepared BFO solution was pulverized onto the substrate maintained at 400 °C on a hot plate, using compressed air as carrier gas. The duration of the deposition was set to 1 h with a rate of 1 mL/min. The substrate was naturally cooled down to room temperature. The thickness of the deposited BFO film was investigated using a profilometer, and an average thickness of 700 nm was observed. To characterize the microstructure of the deposited film, we used the scanning electron microscope (SEM; Environmental Quanta 200 FEG, Thermo Fisher Scientific, Eindhoven, The Netherlands). Further, transmission electron microscopy (TEM) investigation was done on the BFO nanoparticles to investigate the crystallinity and crystal size of the particles. To prepare the TEM specimen, solution of the BFO powder was prepared and sonicated for 3 min and drop casted on a TEM grid (ultra-thin carbon support film, on lacey carbon) and dried. The TEM experiments were done at 300 kV using an image corrected TEM system (Thermo Fisher Scientific, Titan G2, Eindhoven, The Netherlands). The optical properties were studied using a UV-visible-near IR spectrophotometer in the spectral range of 200–1000 nm operating in both reflective and transmission modes. Note that all the photoelectrochemical investigations were carried on BFO film obtained from the initial powder prepared by the second high energy ball milling process.

The photocurrents and Mott–Schottky plots were collected using an electrochemical device (Autolab PGSTAT204, Metrohm, Herisau, Switzerland) coupled to an LED module (LED Driver kit, Metrohm, Herisau, Switzerland). LEDs (450, 470, 505, 590 and 627 nm) with low spectral dispersion are used. These LEDs are calibrated using a photodiode to determine the density of the luminous flux received by the sample. Three electrodes were used for the measurements, including Ag/AgCl and Pt wire acting as a reference electrode and counter electrode, respectively. The working electrode is made of the thin film with a contact fixed on the platinum layer. This connection is not in contact with the electrolyte.
(0.1 M Na$_2$SO$_4$ aqueous solution). The Mott–Schottky curves were recorded at 1 kHz and the applied bias voltage was 0.6 V.

The theoretical calculations were performed using the ab-initio self-consistent full-potential linearized augmented plane wave (FLAPW) method based on the density functional theory (DFT), as implemented in the Wien2K code [89]. Besides, we used the modified generalized gradient (GGA) approximation. However, the GGA approach still underestimates the band gap value, therefore we supplement our calculations using the Tran and Blaha modified Beck–Johnson potential (TB-mBJ), which is known to be an accurate approach giving energy bandgaps values closer to the experimental ones [82,90]. The rhombohedral (R3c) structure was used for our calculations. The lattice parameters used for our calculations were directly extracted from the experimental work. Relaxation of the atomic positions was performed to achieve stable structure. Herein, calculations were performed on bulk and thin film BiFeO$_3$ compounds. Besides, to simulate thin films, we used a vacuum of 10 Å in the z-direction to prohibit periodic conditions.

4. Conclusions

BiFeO$_3$ nanoparticles were synthesized via a high energy ball milling technique and were subsequently deposited using spray pyrolysis method. BiFeO$_3$ thin films were found to have a rhombohedral symmetry (R3c). Such good crystallinity was confirmed by X-ray diffraction and TEM investigations. The BiFeO$_3$ system was found to exhibit 90% of optical absorption in the visible region, which is coherent with the high photocurrent density generated during the photoelectrochemical measurements. The very good catalytic performances achieved, are attributed to the low size of BiFeO$_3$ (sub-20 nm), which in turn lowers the optical band gap and increases the total surface area. Furthermore, the band alignment edges of BiFeO$_3$ thin films as demonstrated by both DFT calculations and experimental measurements suggest that low dimensional BiFeO$_3$ could be used as high preforming photoanodes for water splitting reaction.

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